Hex Buffers

The MC14049UB hex inverter/buffer is constructed with MOS P-channel and N-channel enhancement mode devices in a single monolithic structure. This complementary MOS device finds primary use where low power dissipation and/or high noise immunity is desired. This device provides logic-level conversion using only one supply voltage, V_{DD} . The input-signal high level (V_{IH}) can exceed the V_{DD} supply voltage for logic-level conversions. Two TTL/DTL Loads can be driven when the device is used as CMOS-to-TTL/DTL converters (V_{DD} = 5.0 V, $V_{OL} \leq$ 0.4 V, $I_{OL} \geq$ 3.2 mA). Note that pins 13 and 16 are not connected internally on this device; consequently connections to these terminals will not affect circuit operation.

Features

- High Source and Sink Currents
- High-to-Low Level Converter
- Supply Voltage Range = 3.0 V to 18 V
- Meets JEDEC UB Specifications
- V_{IN} can exceed V_{DD}
- Improved ESD Protection on All Inputs
- These Devices are Pb-Free and are RoHS Compliant

MAXIMUM RATINGS (Voltages Referenced to VSS)

Symbol	Parameter	Value	Unit
V_{DD}	DC Supply Voltage Range	-0.5 to +18.0	V
V _{in}	Input Voltage Range (DC or Transient)	-0.5 to +18.0	V
V _{out}	Output Voltage Range (DC or Transient)	-0.5 to V _{DD} +0.5	V
I _{in}	Input Current (DC or Transient) per Pin	±10	mA
l _{out}	Output Current (DC or Transient) per Pin	+45	mA
P _D	Power Dissipation, per Package (Note 1) Plastic SOIC	825 740	mW
T _A	Ambient Temperature Range	-55 to +125	°C
T _{stg}	Storage Temperature Range	-65 to +150	°C
T _L	Lead Temperature (8-Second Soldering)	260	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Temperature Derating: All Packages: See Figure 4.

This device contains circuitry to protect the inputs against damage due to high static voltages or electric fields referenced to the V_{SS} pin, only. Extra precautions must be taken to avoid applications of any voltage higher than the maximum rated voltages to this high–impedance circuit. For proper operation, the ranges $V_{SS} \leq V_{in} \leq 18 \ V$ and $V_{SS} \leq V_{out} \leq V_{DD}$ are recommended.

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either V_{SS} or V_{DD}). Unused outputs must be left open.



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MARKING DIAGRAMS



PDIP-16 P SUFFIX CASE 648 16<u>ኩሉ ሉ ሉ ሉ ሉ ሉ ለ</u> MC14049UBCP o AWLYYWWG 1 ፑፑፑፑፑፑፑ



SOIC-16 D SUFFIX CASE 751B



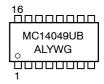


TSSOP-16 DT SUFFIX CASE 948F





SOEIAJ-16 F SUFFIX CASE 966



A = Assembly Location

WL, L = Wafer Lot YY, Y = Year WW, W = Work Week G or ■ = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 3 of this data sheet.

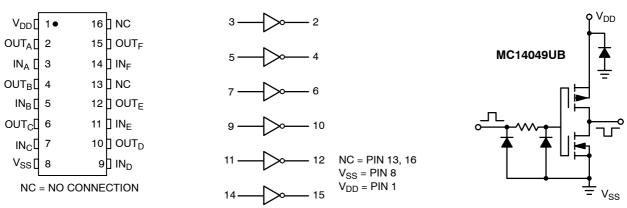


Figure 1. Pin Assignment

Figure 2. Logic Diagram MC14049UB

Figure 3. Circuit Schematic (1/6 of circuit shown)

ELECTRICAL CHARACTERISTICS (Voltages Referenced to V_{SS})

			- 5	5°C		25°C		128	5°C	
Characteristic	Symbol	V _{DD} Vdc	Min	Max	Min	Typ (Note 2)	Max	Min	Max	Unit
Output Voltage "0" Level $V_{in} = V_{DD}$ or 0	V _{OL}	5.0 10 15	- - -	0.05 0.05 0.05	- - -	0 0 0	0.05 0.05 0.05	- - -	0.05 0.05 0.05	Vdc
V_{in} = 0 or V_{DD}	V _{OH}	5.0 10 15	4.95 9.95 14.95	- - -	4.95 9.95 14.95	5.0 10 15	- - -	4.95 9.95 14.95	- - -	Vdc
Input Voltage "0" Level $ (V_O = 4.5 \text{ Vdc}) $ $ (V_O = 9.0 \text{ Vdc}) $ $ (V_O = 13.5 \text{ Vdc}) $	V _{IL}	5.0 10 15	- - -	1.0 2.0 2.5	- - -	2.25 4.50 6.75	1.0 2.0 2.5	- - -	1.0 2.0 2.5	Vdc
$ \text{``Level} \\ \text{(V}_{O} = 0.5 \text{ Vdc)} \\ \text{(V}_{O} = 1.0 \text{ Vdc)} \\ \text{(V}_{O} = 1.5 \text{ Vdc)} $	V _{IH}	5.0 10 15	4.0 8.0 12.5	- - -	4.0 8.0 12.5	2.75 5.50 8.25	- - -	4.0 8.0 12.5	- - -	Vdc
Output Drive Current $ (V_{OH} = 2.5 \text{ Vdc}) $ Source $ (V_{OH} = 9.5 \text{ Vdc}) $ $ (V_{OH} = 13.5 \text{ Vdc}) $	I _{OH}	5.0 10 15	- 1.6 - 1.6 - 4.7	- - -	- 1.25 - 1.3 - 3.75	- 2.5 - 2.6 - 10	- - -	-1.0 -1.0 -3.0	- - -	mAdc
$(V_{OL} = 0.4 \text{ Vdc})$ Sink $(V_{OL} = 0.5 \text{ Vdc})$ $(V_{OL} = 1.5 \text{ Vdc})$	l _{OL}	5.0 10 15	3.75 10 30	- - -	3.2 8.0 24	6.0 16 40	- - -	2.6 6.6 19	- - -	mAdc
Input Current	l _{in}	15	-	± 0.1	-	±0.000 01	± 0.1	-	± 1.0	μAdc
Input Capacitance (V _{in} = 0)	C _{in}	-	-	-	-	10	20	-	-	pF
Quiescent Current (Per Package)	I _{DD}	5.0 10 15	- - -	1.0 2.0 4.0	- - -	0.002 0.004 0.006	1.0 2.0 4.0	- - -	30 60 120	μAdc
Total Supply Current (Note 3 and 4) (Dynamic plus Quiescent, Per Package) (C _L = 50 pF on all outputs, all buffers switching)	I _T	5.0 10 15			$I_{T} = (3.$	8 μΑ/kHz) 5 μΑ/kHz) 3 μΑ/kHz)	f + I _{DD}			μAdc

^{2.} Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

$$I_T(C_L) = I_T(50 \text{ pF}) + (C_L - 50) \text{ Vfk}$$

where: I_T is in μA (per package), C_L in pF, $V = (V_{DD} - V_{SS})$ in volts, f in kHz is input frequency, and k = 0.002.

^{3.} The formulas given are for the typical characteristics only at 25°C.

^{4.} To calculate total supply current at loads other than 50 pF:

SWITCHING CHARACTERISTICS (Note 5) ($C_L = 50 \text{ pF}, T_A = 25^{\circ}\text{C}$)

Characteristic	Symbol	V _{DD} Vdc	Min	Typ (Note 6)	Max	Unit
Output Rise Time	t _{TLH}					ns
$t_{TLH} = (0.8 \text{ ns/pF}) C_L + 60 \text{ ns}$		5.0	_	100	160	
$t_{TLH} = (0.3 \text{ ns/pF}) C_L + 35 \text{ ns}$		10	-	50	100	
$t_{TLH} = (0.27 \text{ ns/pF}) C_L + 26.5 \text{ ns}$		15	-	40	60	
Output Fall Time	t _{THL}					ns
$t_{THL} = (0.3 \text{ ns/pF}) C_L + 25 \text{ ns}$		5.0	_	40	60	
$t_{THL} = (0.12 \text{ ns/pF}) C_L + 14 \text{ ns}$		10	_	20	40	
$t_{THL} = (0.1 \text{ ns/pF}) C_L + 10 \text{ ns}$		15	_	15	30	
Propagation Delay Time	t _{PLH}					ns
$t_{PLH} = (0.38 \text{ ns/pF}) C_L + 61 \text{ ns}$		5.0	_	80	120	
$t_{PLH} = (0.20 \text{ ns/pF}) C_L + 30 \text{ ns}$		10	_	40	65	
$t_{PLH} = (0.11 \text{ ns/pF}) C_L + 24.5 \text{ ns}$		15	-	30	50	
Propagation Delay Time	t _{PHL}					ns
$t_{PHL} = (0.38 \text{ ns/pF}) C_L + 11 \text{ ns}$		5.0	_	30	60	
t _{PHL} = (0.12 ns/PF) C _L + 9 ns		10	_	15	30	
$t_{PHL} = (0.11 \text{ ns/pF}) C_L + 4.5 \text{ ns}$		15	_	10	20	

ORDERING INFORMATION

Device	Package	Shipping [†]
MC14049UBCPG	PDIP-16 (Pb-Free)	500 Units / Tape & Ammunition Box
MC14049UBDG	SOIC-16 (Pb-Free)	48 Units / Rail
MC14049UBDR2G	SOIC-16 (Pb-Free)	2500 / Tape & Reel
MC14049UBDTELG	TSSOP-16*	96 Units / Rail
MC14049UBDTR2G	TSSOP-16*	2500 / Tape & Reel
MC14049UBFELG	SOEIAJ-16 (Pb-Free)	2000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}This package is inherently Pb-Free.

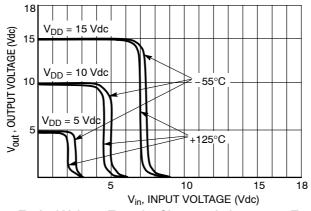


Figure 4. Typical Voltage Transfer Characteristics versus Temperature

^{5.} The formulas given are for the typical characteristics only at 25°C.
6. Data labelled "Typ" is not to be used for design purposes but is intended as an indication of the IC's potential performance.

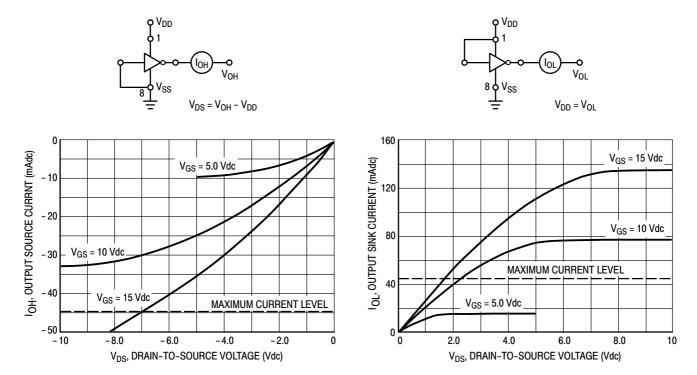


Figure 5. Typical Output Source Characteristics

Figure 6. Typical Output Sink Characteristics

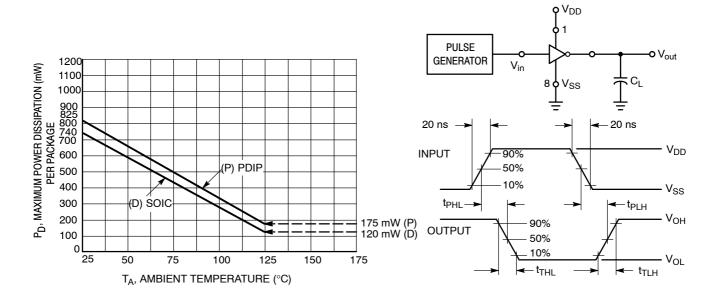
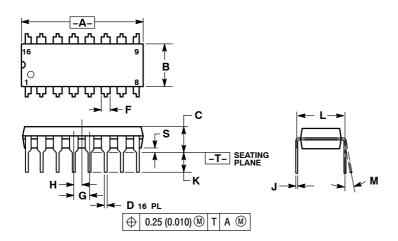


Figure 7. Ambient Temperature Power Derating

Figure 8. Switching Time Test Circuit and Waveforms

PACKAGE DIMENSIONS

PDIP-16 **P SUFFIX** PLASTIC DIP PACKAGE CASE 648-08 ISSUE T

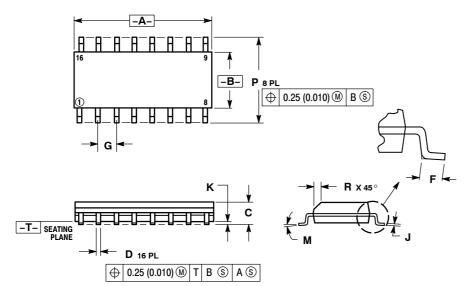


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
 5. ROUNDED CORNERS OPTIONAL.

		INC	HES	MILLIN	IETERS
	DIM	MIN	MAX	MIN	MAX
	Α	0.740	0.770	18.80	19.55
	В	0.250	0.270	6.35	6.85
	С	0.145	0.175	3.69	4.44
	D	0.015	0.021	0.39	0.53
	F	0.040	0.70	1.02	1.77
	G	0.100	BSC	2.54 BSC	
L	Н	0.050	BSC	1.27	BSC
	J	0.008	0.015	0.21	0.38
	K	0.110	0.130	2.80	3.30
	L	0.295	0.305	7.50	7.74
	М	0°	10 °	0 °	10 °
	S	0.020	0.040	0.51	1.01

PACKAGE DIMENSIONS

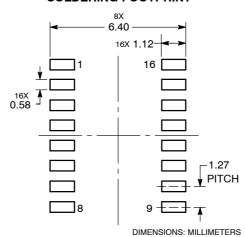
SOIC-16 **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751B-05 ISSUE K



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTECTION OF THE PROTECTION OF THE PROTECTION OF THE PROTECTION OF THE PROT
- PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- MAXIMUM MUCLI PROTHOLOGION 0.19 (LOUGH) FER SIDE DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	9.80	10.00	0.386	0.393
В	3.80	4.00	0.150	0.157
С	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050	BSC
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.229	0.244
R	0.25	0.50	0.010	0.019

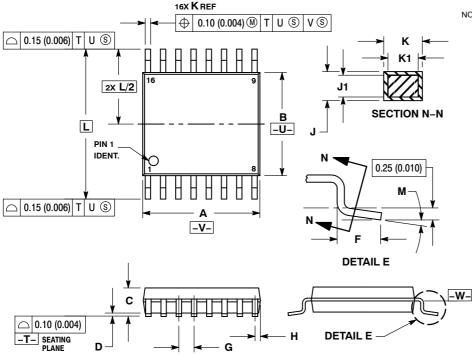
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

TSSOP-16 **DT SUFFIX** PLASTIC TSSOP PACKAGE CASE 948F-01 **ISSUE B**



NOTES:

- JIES:

 1. DIMENSIONING AND TOLERANCING PER
 ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD
 FLASH. PROTRUSIONS OR GATE BURRS.
 MOLD FLASH OR GATE BURRS SHALL NOT
 EXCEED 15 (2008) DED SIDE.
- MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

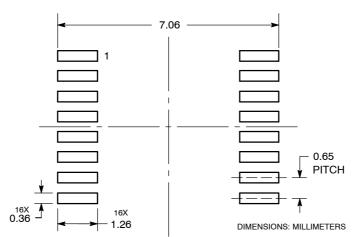
 5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.

 6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.

 7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE —W—.

	MILLIN	IETERS	INC	HES		
DIM	MIN	MAX	MIN	MAX		
Α	4.90	5.10	0.193	0.200		
В	4.30	4.50	0.169	0.177		
С		1.20		0.047		
D	0.05	0.15	0.002	0.006		
F	0.50	0.75	0.020	0.030		
G	0.65	BSC	0.026	BSC		
Н	0.18	0.28	0.007	0.011		
J	0.09	0.20	0.004	0.008		
J1	0.09	0.16	0.004	0.006		
K	0.19	0.30	0.007	0.012		
K1	0.19	0.25	0.007	0.010		
L	6.40	BSC	0.252 BSC			
М	0 °	8 °	0°	8 °		

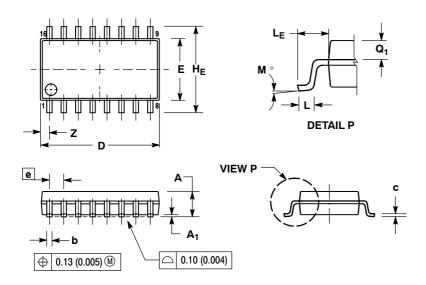
SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SOEIAJ-16 **F SUFFIX** PLASTIC EIAJ SOIC PACKAGE CASE 966-01 **ISSUE A**



NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 CONTROLLING DIMENSION: MILLIMETER.
- DIMENSIONS D AND E DO NOT INCLUDE
 MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
- TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- 5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION.

 DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE
 BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α		2.05		0.081
A ₁	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
С	0.10	0.20	0.007	0.011
D	9.90	10.50	0.390	0.413
Ε	5.10	5.45	0.201	0.215
е	1.27	BSC	0.050	BSC
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0 °	10°	0 °	10 °
Q_1	0.70	0.90	0.028	0.035
Z	-	0.78		0.031

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